

| Form PTO-1449 U.S. DEPARTMENT OF COMMERCE (REV. 8-83) PATENT AND TRADEMARK OFFICE | | | | ATTY. DOCKET NO. BUR920010088US1 | | SERIAL NO. 09/683,278 | |
|--|-----------------|--|---------|-------------------------------------|-----------|--------------------------|----------------------------|
| | | | | APPLICANT Breitwisch, et al. | | | |
| INFORMATION DISCLOSURE CITATION <small>(Use several sheets if necessary)</small> | | | | FILING DATE 12/7/2001 | | GROUP | |
| U. S. PATENT DOCUMENTS | | | | | | | |
| EXAMINER INITIAL | REF | DOCUMENT NUMBER | DATE | NAME | CLASS | SUB-CLASS | FILING DATE IF APPROPRIATE |
| | | 6,194,258 | 02/2001 | Wuu | | | |
| | | 6,160,282 | 12/2000 | Merrill | | | |
| | | 6,057,215 | 05/2000 | Kitano | | | |
| | | 6,051,864 | 04/2000 | Hodges, et al. | | | |
| | | 6,020,242 | 01/2000 | Tsai, et al. | | | |
| | | 5,973,382 | 10/1999 | Burgener, et al. | | | |
| | | 4,656,731 | 04/1987 | Lam, et al. | | | |
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| | | | | | | YES | NO |
| | | | | | | | |
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| OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.) | | | | | | | |
| | | R.D. Isaac, "The Future of CMOS Technology", 3 May 2000, Vol. 44, pp. 369-378. | | | | | |
| EXAMINER | | | | DATE CONSIDERED | | | |
| *EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | | | | | | | |